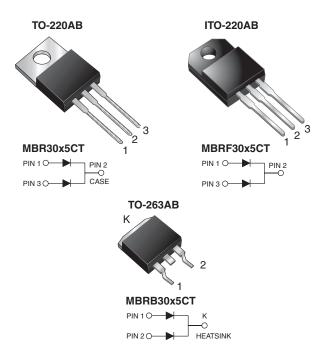
MBR30x5CT, MBRF30x5CT, MBRB30x5CT

Vishay General Semiconductor

RoHS COMPLIANT

Dual Common Cathode Schottky Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V_{RRM}	35 V to 45 V				
I _{FSM}	200 A				
V_{F}	0.60 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

FEATURES

Power pack



- Low power loss, high efficiency
- Low forward voltage drop
- · High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR3035CT	MBR3045CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	35	45		
Working peak reverse voltage		V_{RWM}	35	45	V	
Maximum DC blocking voltage		V_{DC}	35	45		
Maximum average forward rectified current	total device	ı	30			
	per diode	I _{F(AV)}	15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	200		Α	
Peak repetitive reverse current per diode at t _p = 2.0 µs, 1 kHz		I _{RRM}	2.0			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction temperature range		T _J -65 to +150		°C		
Storage temperature range	ge temperature range		-65 to +175		C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	15	00	V	



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
		I _F = 20 A	T _C = 125°C	0.60		
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 30 A	$T_C = 25^{\circ}C$	0.76	V	
		I _F = 30 A	T _C = 125°C	0.72		
Maximum instantaneous reverse current at DC blocking voltage per diode	I _R ⁽¹⁾	Rated V _R	T _J = 25 °C	1.0	- mA	
			T _J = 125 °C	60		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR3045CT-E3/45	1.85	45	50/tube	Tube		
TO-220AB	MBR3045CT-E3/4W	1.85	4W	50/tube	Tube		
ITO-220AB	MBRF3045CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB3045CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB3045CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR3045CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF3045CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB3045CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB3045CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		
TO-263AB	MBRB3045CTHE3_A/P (1)	1.35	Р	50/tube	Tube		
TO-263AB	MBRB3045CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

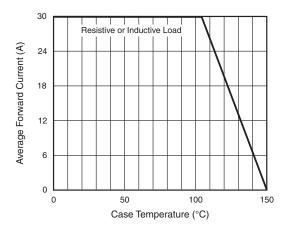


Fig. 1 - Forward Current Derating Curve

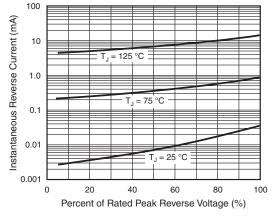


Fig. 4 - Typical Reverse Characteristics Per Diode

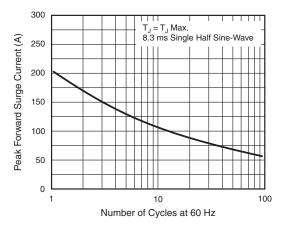


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

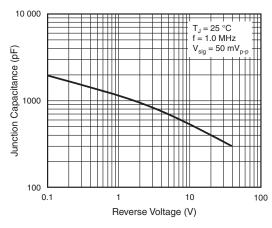


Fig. 5 - Typical Junction Capacitance Per Diode

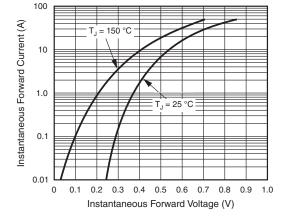


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

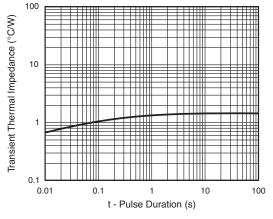


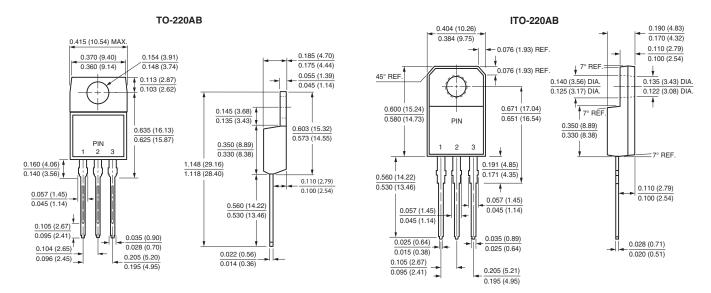
Fig. 6 - Typical Transient Thermal Impedance Per Diode

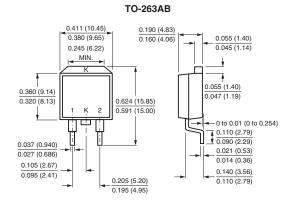


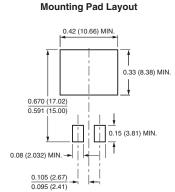
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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